



DL-7140-201

## High Power Laser Diode

## Overview

DL-7140-201 is high power (70mW) 785nm laser diode.  
DL-7140-201 is suitable for CD-R.

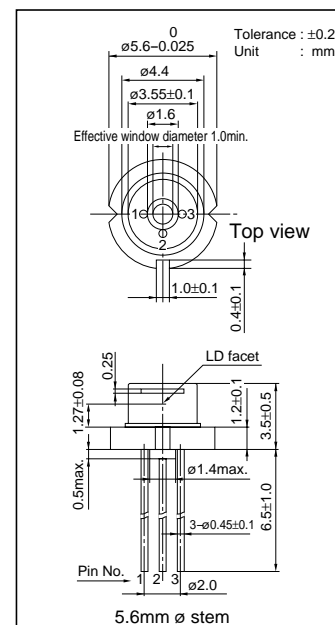
## Features

- High power : 70 mW at 60°C
- Index guided type
- Small package : 5.6 mm $\varnothing$
- PIN connection : Cathode common type

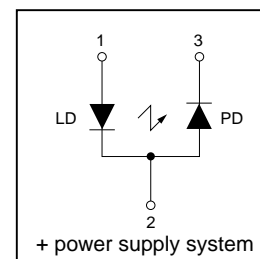
## Absolute Maximum Ratings at Tc=25°C

Parameter	Symbol	Ratings	Unit
Light Output	Po	80	mW
Reverse Voltage	Laser PIN	VR	2
			30
Operating Temperature	Topr	-10 to +60	°C
Storage Temperature	Tstg	-40 to +85	°C

## Package Dimensions



## Electrical Connection



## Electrical and Optical Characteristics at Tc=25°C

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	
Threshold Current	Ith	CW	-	30	50	mA	
Operating Current	Iop	Po=70mW	-	100	140	mA	
Operating Voltage	Vop	Po=70mW	-	2.0	2.5	V	
Lasing Wavelength	$\lambda_p$	Po=70mW	780	785	800	nm	
Beam Divergence	Perpendicular	$\theta_{\perp}$	Po=70mW	15	17	20	deg.
	Parallel	$\theta_{//}$	Po=70mW	5.5	7.0	8.0	deg.
Off Axis Angle	Perpendicular	$\Delta\theta_{\perp}$	-	-	±3	deg.	
	Parallel	$\Delta\theta_{//}$	-	-	±3	deg.	
Differential Efficiency	dPo/dIop	-	0.6	1.0	1.4	mW/mA	
Monitoring Output Current	Im	Po=70mW	0.10	0.25	0.60	mA	
Astigmatism	As	Po=70mW	-	10	-	$\mu\text{m}$	

\*) Full angle at half maximum note : The above product specifications are subject to change without notice.

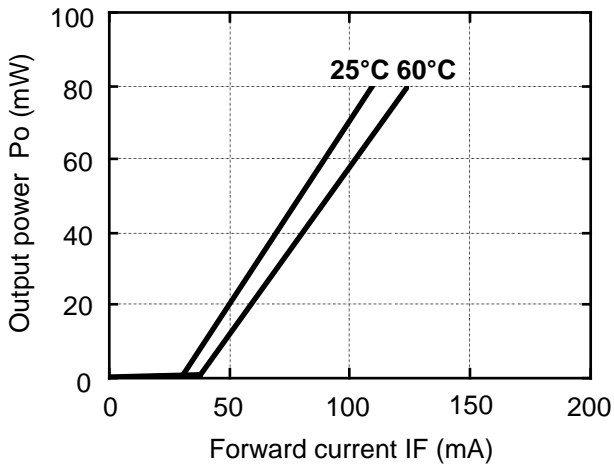
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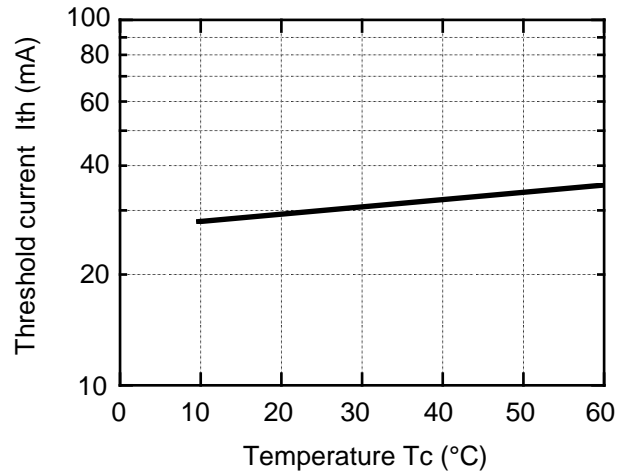
N2798 GI / N2897 GI, (IM) No.5873 1/3

## Characteristics

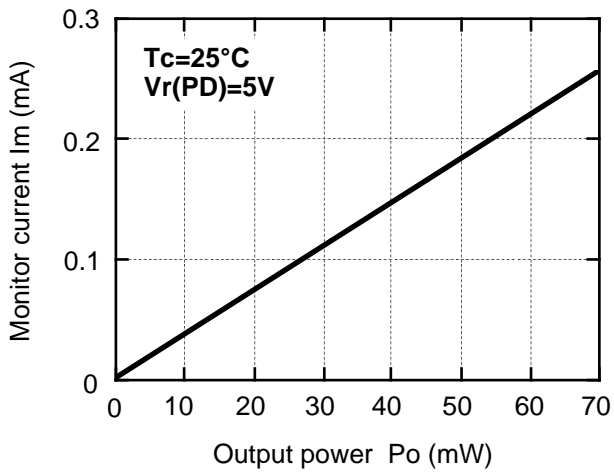
### Output power vs. Forward current



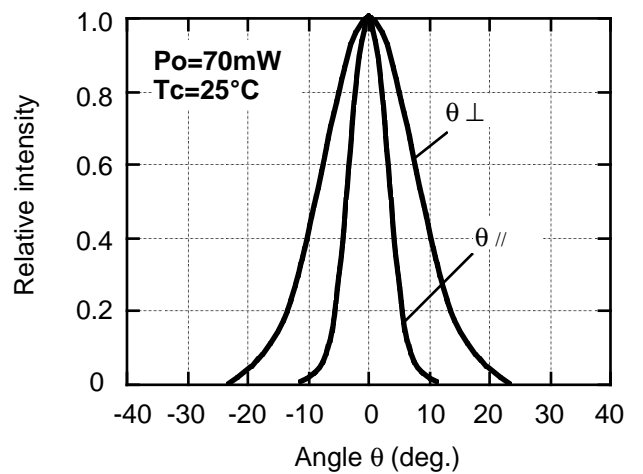
### Threshold current vs. Temperature



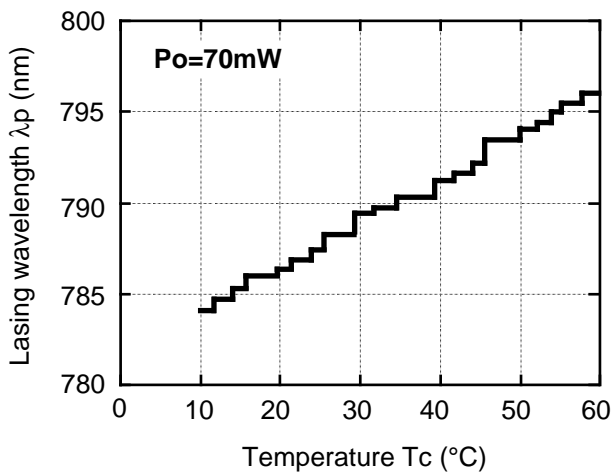
### Monitor current vs. Output power



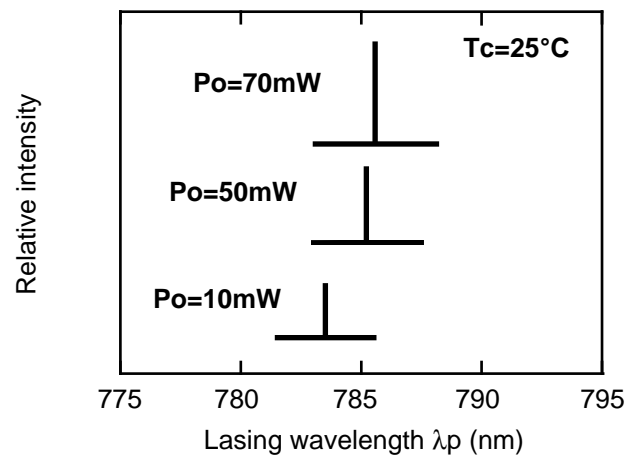
### Beam divergence



### Lasing wavelength vs. Temperature



### Output power vs. Lasing wavelength



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## Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

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